

TOSHIBA Transistor Silicon NPN Epitaxial Type (Darlington power transistor)

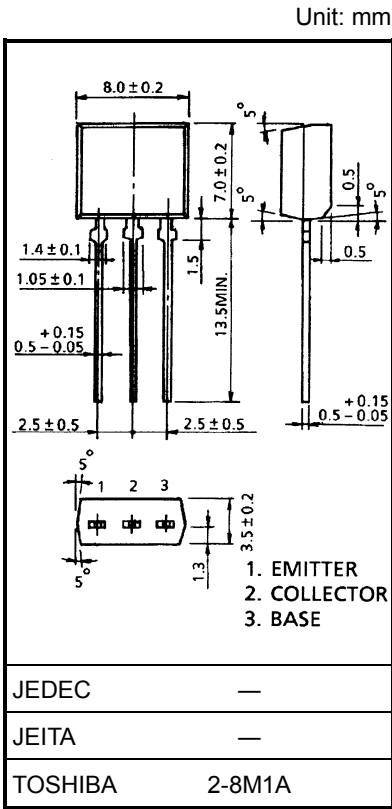
2SD2480

Micro Motor Drive, Hammer Drive Applications
Switching Applications
Power Amplifier Applications

- High DC current gain: $h_{FE} = 2000$ (min) ($V_{CE} = 2\text{ V}$, $I_C = 1\text{ A}$)
- Low saturation voltage: $V_{CE(sat)} = 1.5\text{ V}$ (max) ($I_C = 1\text{ A}$, $I_B = 1\text{ mA}$)

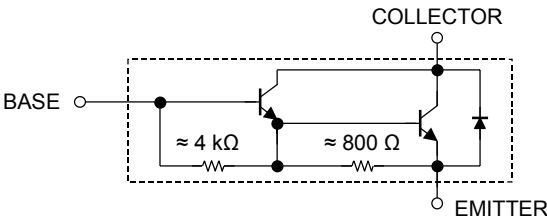
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEO}	100	V
Emitter-base voltage		V_{EBO}	8	V
Collector current	DC	I_C	2	A
	Pulse	I_{CP}	3	
Base current		I_B	0.5	A
Collector power dissipation		P_C	1.3	W
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

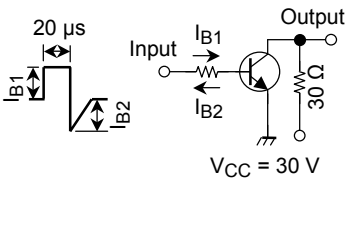


Weight: 0.55 g (typ.)

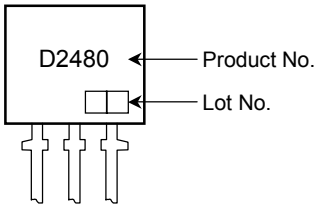
Equivalent Circuit



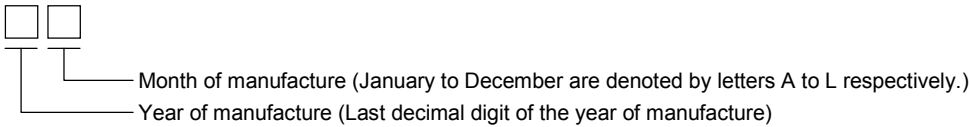
Electrical Characteristics (Ta = 25°C)

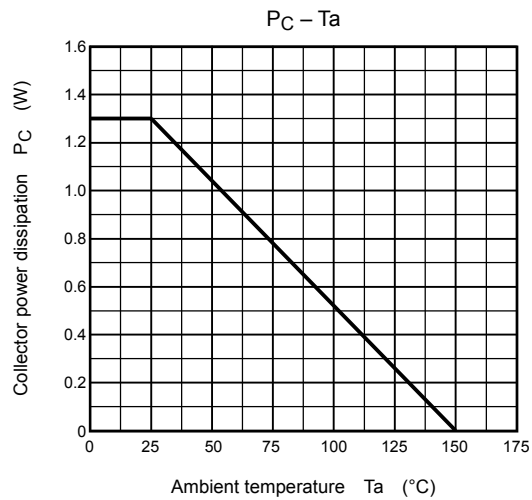
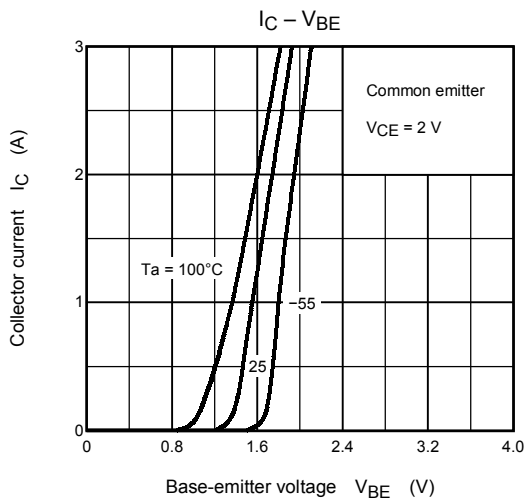
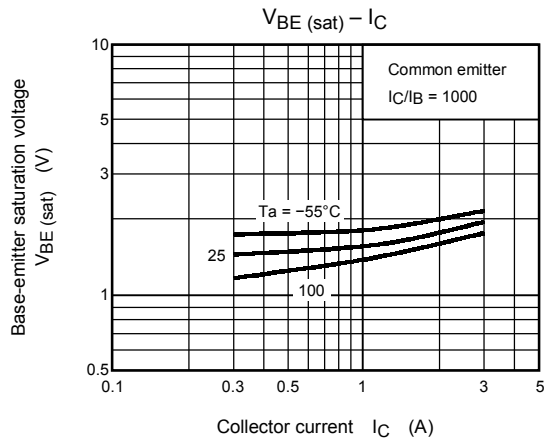
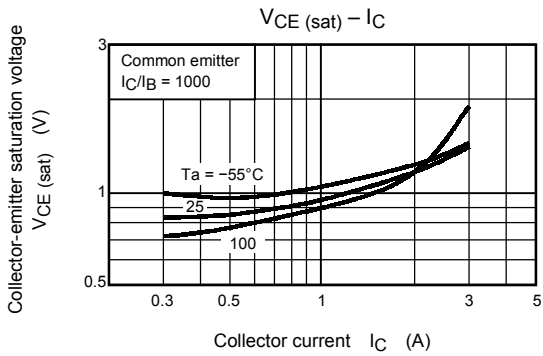
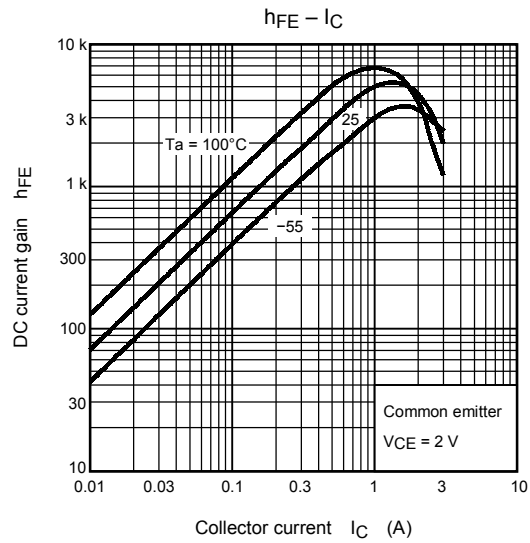
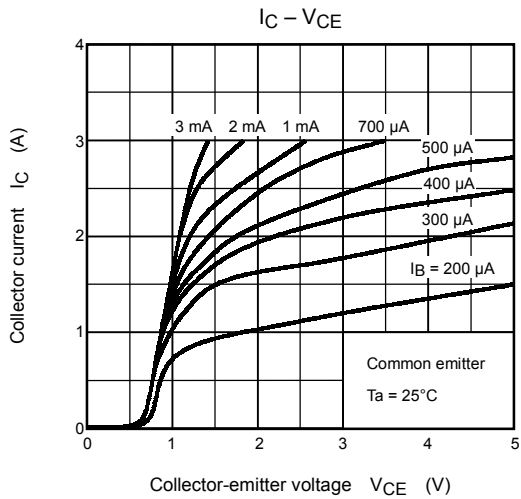
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		ICBO	V _{CB} = 80 V, I _E = 0	—	—	10	μA
Emitter cut-off current		IEBO	V _{EB} = 8 V, I _C = 0	—	—	4	mA
Collector-emitter breakdown voltage		V _(BR) CEO	I _C = 10 mA, I _B = 0	100	—	—	V
DC current gain		h _{FE}	V _{CE} = 2 V, I _C = 1 A (pulse)	2000	—	—	
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 1 A, I _B = 1 mA (pulse)	—	—	1.5	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 1 A, I _B = 1 mA (pulse)	—	—	2.0	V
Transition frequency		f _T	V _{CE} = 2 V, I _C = 0.5 A	—	100	—	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	—	20	—	pF
Switching time	Turn-on time	t _{on}	 I _{B1} = -I _{B2} = 1 mA, duty cycle ≤ 1%	—	0.4	—	μs
	Storage time	t _{stg}		—	4.0	—	
	Fall time	t _f		—	0.6	—	

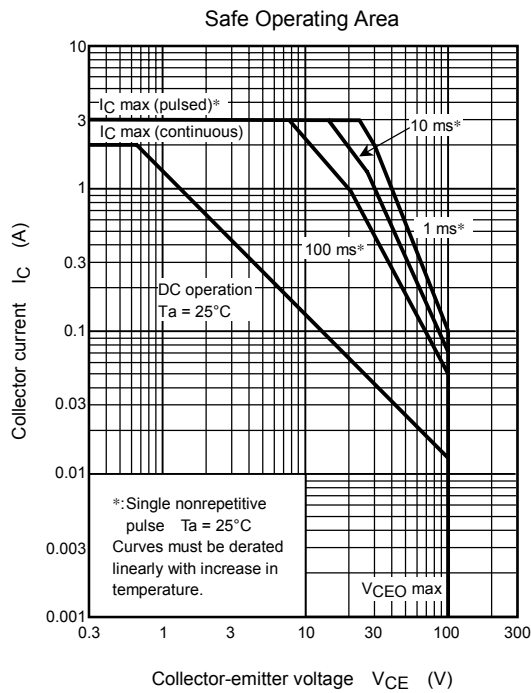
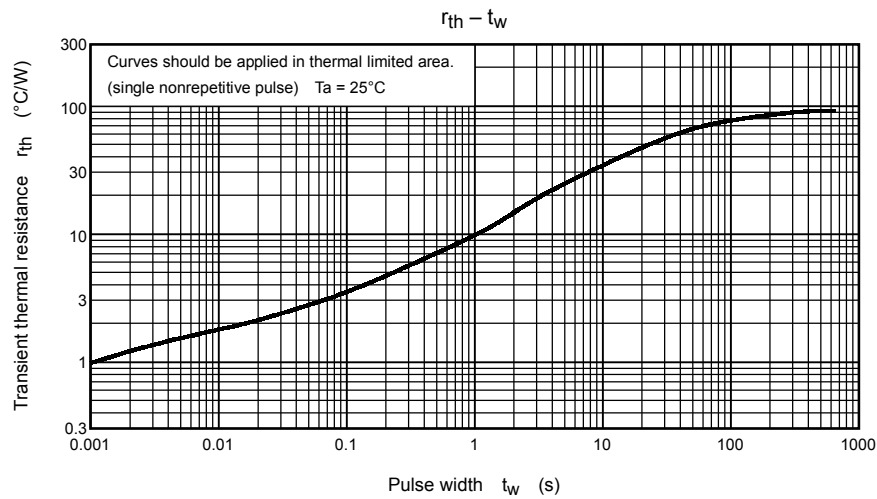
Marking



Explanation of Lot No.







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